

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







## **EFC6605R**

# ON Semiconductor®

# N-Channel Power MOSFET 20V, 10A, 13.3mΩ, Dual EFCP

http://onsemi.com

#### **Features**

- 2.5V drive
- Protection diode in
- Halogen free compliance

- Common-drain type
- 2KV ESD HBM

#### **Applications**

• Lithium-ion battery charging and discharging switch

#### **Specifications**

**Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>		20	V
Gate to Source Voltage	V <sub>GSS</sub>		±10	٧
Source Current (DC)	IS		10	Α
Source Current (Pulse)	I <sub>SP</sub>	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm <sup>2</sup> ×0.8mm)	1.6	W
Junction Temperature	Tį		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **Thermal Resistance Ratings**

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	78.1	°C /W
When mounted on ceramic substrate (5000mm <sup>2</sup> ×0.8mm)			

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Cumbal	Conditions		Value			Unit
Parameter	Symbol			min	typ	max	Offic
Source to Source Breakdown Voltage	V(BR)SSS	I <sub>S</sub> =1mA, V <sub>GS</sub> =0V	Test Circuit 1	20			V
Zero-Gate Voltage Source Current	ISSS	V <sub>SS</sub> =20V, V <sub>GS</sub> =0V	Test Circuit 1			1	μА
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>SS</sub> =0V	Test Circuit 2			±1.0	μА
Gate Threshold Voltage	V <sub>GS</sub> (th)	V <sub>SS</sub> 10V, I <sub>S</sub> =1mA	Test Circuit 3	0.5		1.3	٧
Forward Transconductance	9FS	V <sub>SS</sub> =10V, I <sub>S</sub> =3A	Test Circuit 4		11.4		S
	RSS(on)1	IS=3A, VGS=4.5V	Test Circuit 5	8.8	11.1	13.3	mΩ
	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	9.1	11.4	13.7	mΩ
Static Source to Source On-State Resistance	RSS(on)3	IS=3A, VGS=3.8V	Test Circuit 5	9.3	11.6	13.9	mΩ
nesistance	RSS(on)4	IS=3A, VGS=3.1V	Test Circuit 5	10.0	12.5	15.6	mΩ
	RSS(on)5	IS=3A, VGS=2.5V	Test Circuit 5	11.1	13.9	17.4	mΩ

Continued on next page.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### **EFC6605R**

Continued from preceding page.

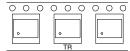
Parameter	0	O and disking a	Value			11.3
	Symbol Conditions		min	typ	max	Unit
Turn-ON Delay Time	t <sub>d</sub> (on)			154		ns
Rise Time	t <sub>r</sub>	V 40V V 45V I- 04 T-+ 0im-vit 0		678		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	VSS=10V, VGS=4.5V, IS=3A Test Circuit 6		44400		ns
Fall Time	tf			60800		ns
Total Gate Charge	Qg	V <sub>SS</sub> =10V, V <sub>GS</sub> =4.5V, I <sub>S</sub> =10A Test Circuit 7		19.8		nC
Forward Source to Source Voltage	V <sub>F(S-S)</sub>	I <sub>S</sub> =3A, V <sub>GS</sub> =0V Test Circuit 8		0.75	1.2	٧

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

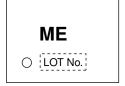
#### **Ordering & Package Information**

Device	Package	Shipping	note
EFC6605R-TR	EFCP	5,000 pcs. / reel	Pb-Free and Halogen Free

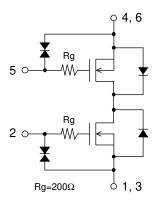
#### Packing Type: TR



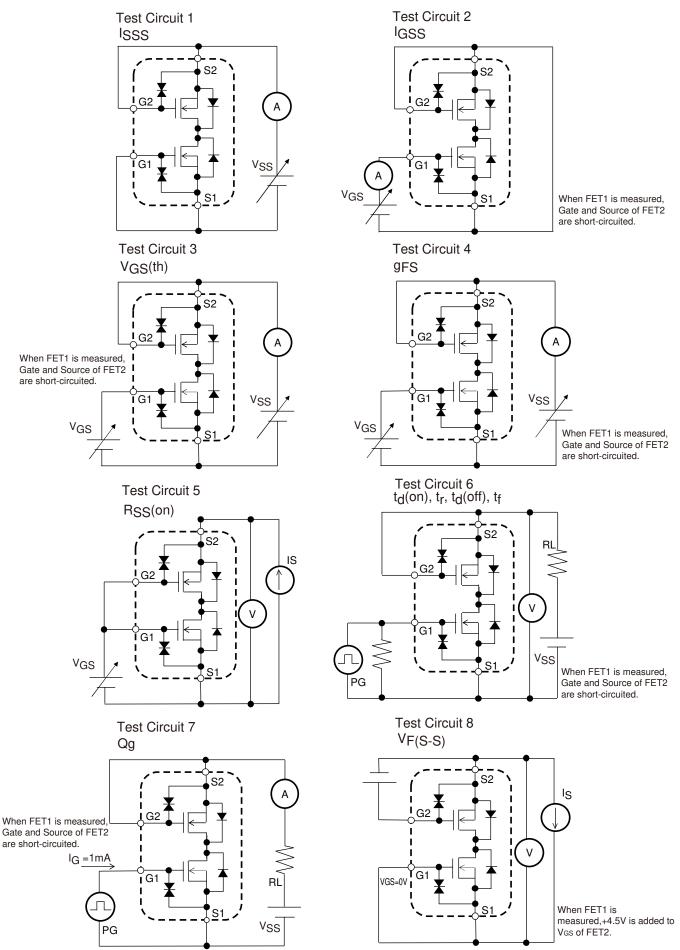
#### Marking



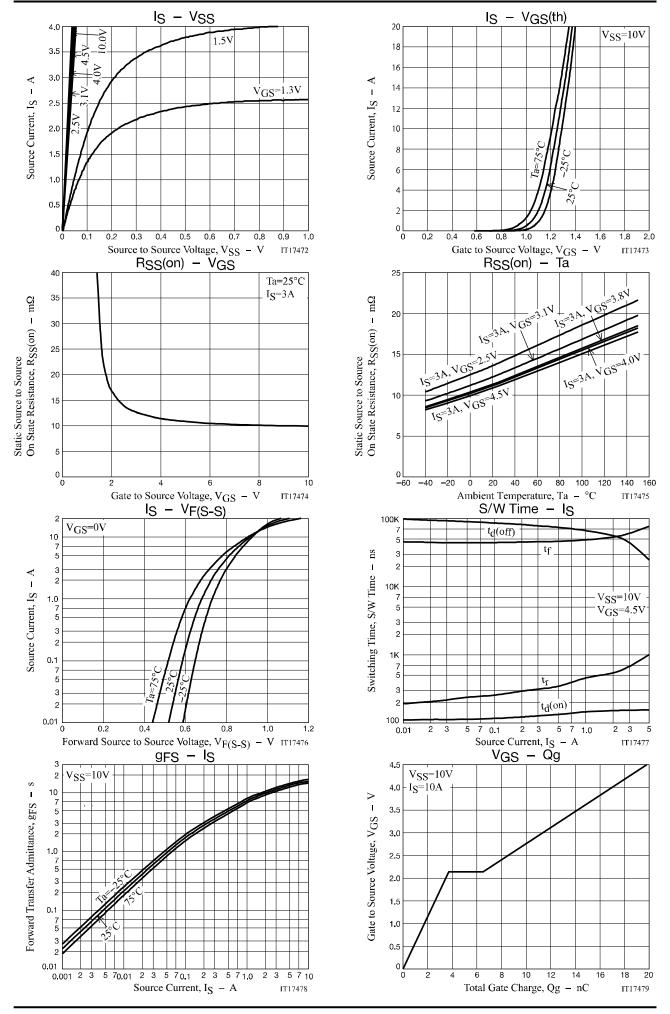
#### **Electrical Connection**



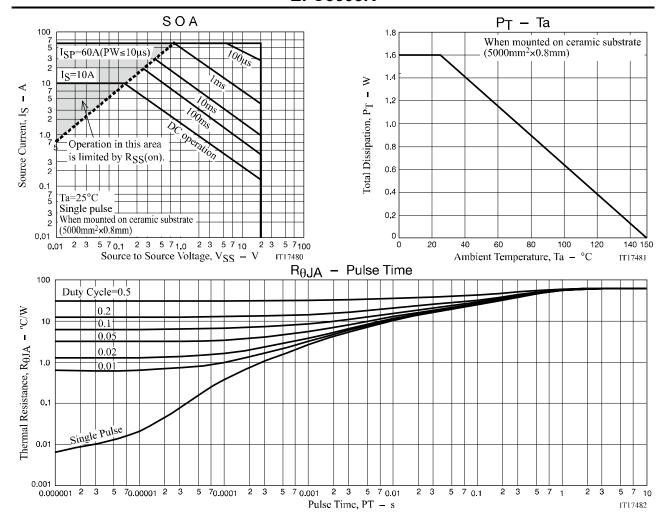
#### Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.



#### **EFC6605R**



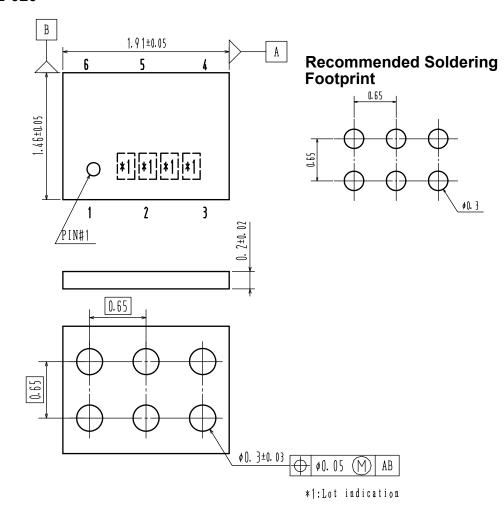
#### **Package Dimensions**

EFC6605R-TR

#### EFCP1915-6CE-020

unit: mm

- 1: Source1
- 2: Gate1
- 3: Source1
- 4: Source2
- 5: Gate2
- 6: Source2



Note on usage: Since the EFC6605R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equa